

BD239/A/B/C

Medium Power Linear and Switching Applications

Complement to BD240/A/B/C respectively



NPN Epitaxial Silicon Transistor

1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage		
	: BD239	45	V
	: BD239A	60	V
	: BD239B	80	V
	: BD239C	100	V
V _{CER}	Collector-Emitter Voltage		
	: BD239	55	V
	: BD239A	70	V
	: BD239B	90	V
	: BD239C	115	V
√ _{EBO}	Emitter-Base Voltage	5	V
С	Collector Current (DC)	2	Α
СР	*Collector Current (Pulse)	4	Α
В	Base Current	0.6	Α
Pc	Collector Dissipation (T _C =25°C)	30	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

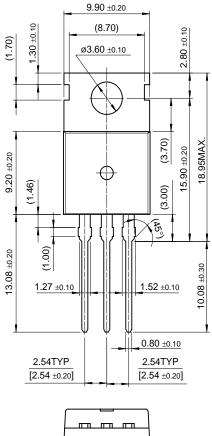
Electrical Characteristics T_C=25°C unless otherwise noted

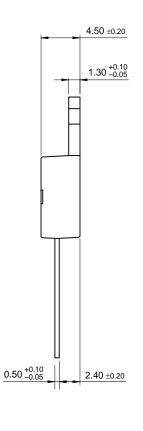
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	*Collector-Emitter Sustaining Voltage					
	: BD239	$I_C = 30 \text{mA}, I_B = 0$	45			V
	: BD239A		60			V
	: BD239B		80			V
	: BD239C		100			V
I _{CEO}	Collector Cut-off Current					
020	: BD239/A	$V_{CE} = 30V, I_{B} = 0$			0.3	mA
	: BD239B/C	$V_{CE} = 60V, I_{B} = 0$			0.3	mA
I _{CES}	Collector Cut-off Current					
	: BD239	$V_{CE} = 45V, V_{BE} = 0$			0.2	mA
	: BD239A	$V_{CE} = 60V, V_{BE} = 0$			0.2	mA
	: BD239B	$V_{CE} = 80V, V_{BE} = 0$			0.2	mA
	: BD239C	$V_{CE} = 100V, V_{BE} = 0$			0.2	mA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			1	mA
h _{FE}	*DC Current Gain	$V_{CE} = 4V, I_{C} = 0.2A$	40			
		$V_{CE} = 4V, I_{C} = 1A$	15			
V _{CE} (sat)	*Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$			0.7	V
V _{RF} (on)	*Base-Emitter ON Voltage	$V_{CF} = 4V, I_{C} = 1A$			1.3	V

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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